



NHDTC123JT/143ZT/114YT-Q series

80 V, 100 mA NPN resistor-equipped transistors

Rev. 1 — 9 October 2024

Product data sheet

1. General description

NPN Resistor-Equipped Transistor (RET) family in a small SOT23 Surface-Mounted Device (SMD) plastic package.

Table 1. Product overview

Type number	R1	R2	Package	PNP complement:
	k Ω	k Ω	Nexperia	
NHDTC123JT-Q	2.2	47	SOT23	NHDTA123JT-Q
NHDTC143ZT-Q	4.7	47		NHDTA143ZT-Q
NHDTC114YT-Q	10	47		NHDTA114YT-Q

2. Features and benefits

- 100 mA output current capability
- High breakdown voltage
- Built-in resistors
- Simplifies circuit design
- Reduces component count
- Reduces pick and place costs
- Qualified according to AEC-Q101 and recommended for use in automotive applications

3. Applications

- Digital applications
- Cost saving alternative for BC846 series in digital applications
- Controlling IC inputs
- Switching loads

4. Quick reference data

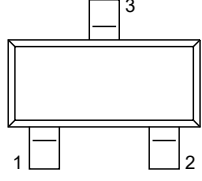
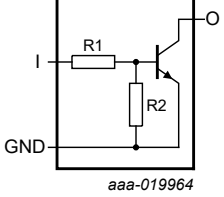
Table 2. Quick reference data

$T_{amb} = 25\text{ }^{\circ}\text{C}$ unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{CEO}	collector-emitter voltage	open base	-	-	80	V
I_O	output current		-	-	100	mA

5. Pinning information

Table 3. Pinning

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	I	input (base)		
2	GND	GND (emitter)		
3	O	output (collector)		

6. Ordering information

Table 4. Ordering information

Type number	Package		
	Name	Description	Version
NHDTC123JT-Q	SOT23	plastic surface-mounted package; 3 leads	SOT23
NHDTC143ZT-Q			
NHDTC114YT-Q			

7. Marking

Table 5. Marking

Type number	Marking code [1]
NHDTC123JT-Q	QJ%
NHDTC143ZT-Q	QL%
NHDTC114YT-Q	QH%

[1] % = placeholder for manufacturing site code

8. Limiting values

Table 6. Limiting values

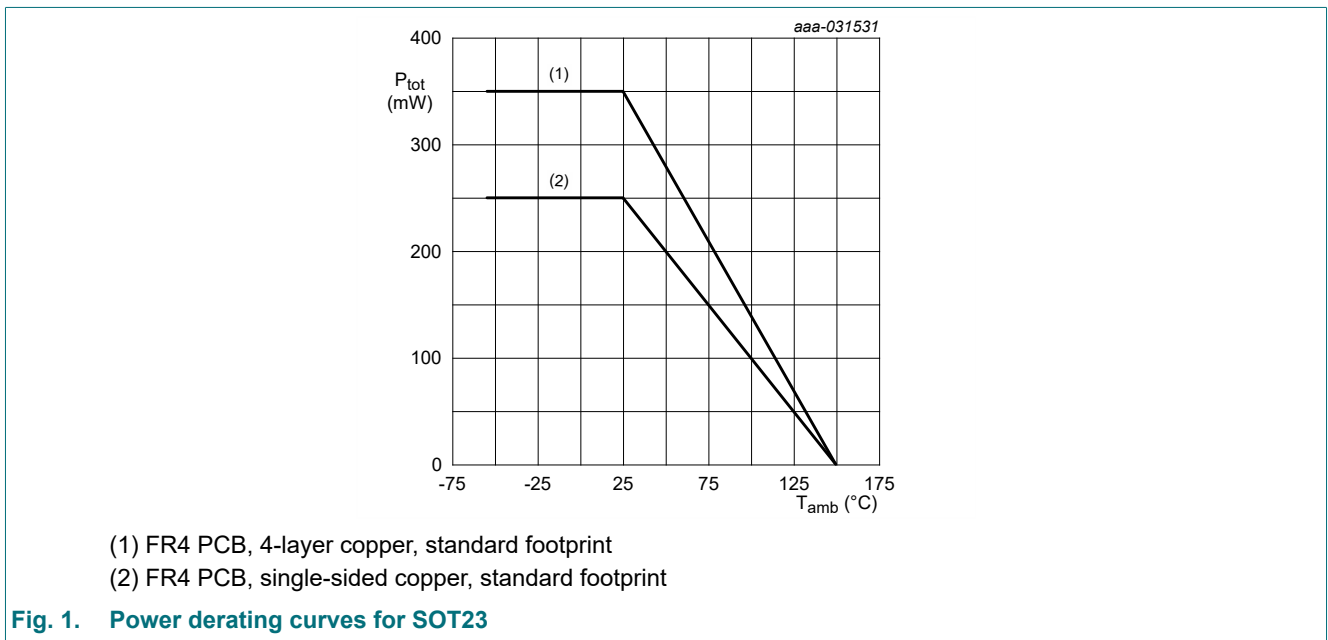
In accordance with the Absolute Maximum Rating System (IEC 60134).

$T_{amb} = 25\text{ °C}$ unless otherwise specified.

Symbol	Parameter	Conditions	Min	Max	Unit	
V_{CBO}	collector-base voltage	open emitter	-	80	V	
V_{CEO}	collector-emitter voltage	open base	-	80	V	
V_{EBO}	emitter-base voltage	open collector	-	7	V	
V_i	input voltage					
	NHDTC123JT-Q		-7	+20	V	
	NHDTC143ZT-Q		-7	+30	V	
	NHDTC114YT-Q		-7	+40	V	
I_O	output current		-	100	mA	
P_{tot}	total power dissipation	$T_{amb} \leq 25\text{ °C}$	[1]	-	250	mW
			[2]	-	350	mW
T_j	junction temperature		-	150	°C	
T_{amb}	ambient temperature		-55	150	°C	
T_{stg}	storage temperature		-65	150	°C	

[1] Device mounted on an FR4 Printed-Circuit-Board (PCB); single-sided copper; tin-plated and standard footprint.

[2] Device mounted on an FR4 Printed-Circuit-Board (PCB); 4-layer copper; tin-plated and standard footprint.



9. Thermal characteristics

Table 7. Thermal characteristics

$T_{amb} = 25\text{ °C}$ unless otherwise specified.

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	500	K/W
			[2]	-	-	358	K/W
$R_{th(j-sp)}$	thermal resistance from junction to solder point			-	-	130	K/W

[1] Device mounted on an FR4 Printed-Circuit-Board (PCB); single-sided copper; tin-plated and standard footprint.

[2] Device mounted on an FR4 Printed-Circuit Board (PCB), 4-layer copper, tin-plated and standard footprint.

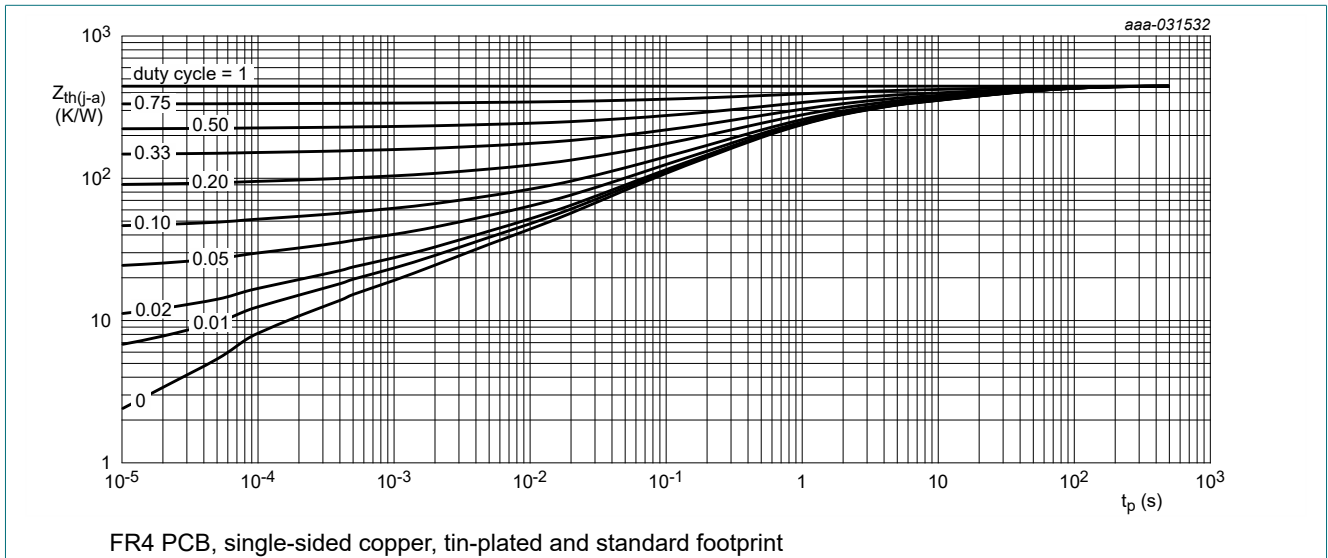


Fig. 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

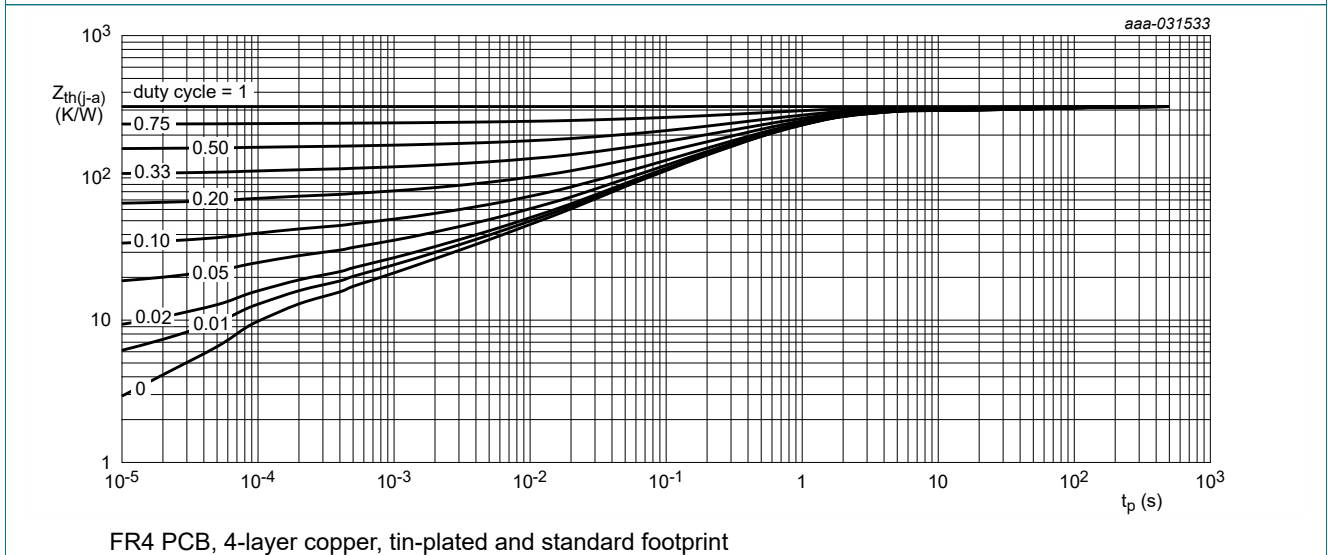


Fig. 3. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

10. Characteristics

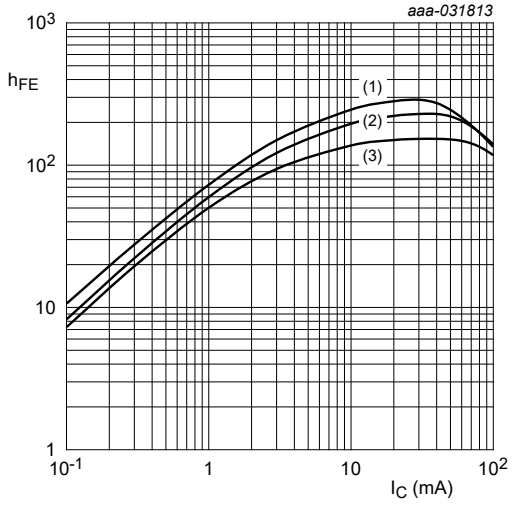
Table 8. Characteristics

$T_{amb} = 25\text{ °C}$ unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit	
$V_{(BR)CBO}$	collector-base breakdown voltage	$I_C = 100\ \mu\text{A}; I_E = 0\ \text{A}$	80	-	-	V	
$V_{(BR)CEO}$	collector-emitter breakdown voltage	$I_C = 2\ \text{mA}; I_B = 0\ \text{A}$	80	-	-	V	
I_{CBO}	collector-base cut-off current	$V_{CB} = 80\ \text{V}; I_E = 0\ \text{A}$	-	-	100	nA	
I_{CEO}	collector-emitter cut-off current	$V_{CE} = 60\ \text{V}; I_B = 0\ \text{A}$	-	-	100	nA	
		$V_{CE} = 60\ \text{V}; I_B = 0\ \text{A}; T_j = 150\text{ °C}$	-	-	5	μA	
I_{EBO}	emitter-base cut-off current						
	NHDTC123JT-Q	$V_{EB} = 7\ \text{V}; I_C = 0\ \text{A}$	-	-	270	μA	
	NHDTC143ZT-Q		-	-	260	μA	
	NHDTC114YT-Q		-	-	230	μA	
h_{FE}	DC current gain	$V_{CE} = 5\ \text{V}; I_C = 10\ \text{mA}$	100	-	-		
V_{CEsat}	collector-emitter saturation voltage	$I_C = 10\ \text{mA}; I_B = 0.5\ \text{mA}$	-	-	100	mV	
$V_{I(off)}$	off-state input voltage						
	NHDTC123JT-Q	$V_{CE} = 5\ \text{V}; I_C = 100\ \mu\text{A}$	-	595	500	mV	
	NHDTC143ZT-Q		-	625	500	mV	
	NHDTC114YT-Q		-	690	500	mV	
$V_{I(on)}$	on-state input voltage						
	NHDTC123JT-Q	$V_{CE} = 0.3\ \text{V}; I_C = 10\ \text{mA}$	1.2	0.81	-	V	
	NHDTC143ZT-Q		1.4	0.95	-	V	
	NHDTC114YT-Q		1.6	1.22	-	V	
R1	bias resistor 1 (input)						
	NHDTC123JT-Q		[1]	1.54	2.2	2.86	k Ω
	NHDTC143ZT-Q			3.3	4.7	6.1	k Ω
	NHDTC114YT-Q			7	10	13	k Ω
R2/R1	bias resistor ratio						
	NHDTC123JT-Q		[1]	17	21	26	
	NHDTC143ZT-Q			8	10	12	
	NHDTC114YT-Q			3.7	4.7	5.7	
f_T	transition frequency	$V_{CE} = 5\ \text{V}; I_C = 10\ \text{mA}; f = 100\ \text{MHz}$	[2]	-	170	-	MHz
C_c	collector capacitance	$V_{CB} = 10\ \text{V}; I_E = I_e = 0\ \text{A}; f = 1\ \text{MHz}$	-	-	2.5	pF	

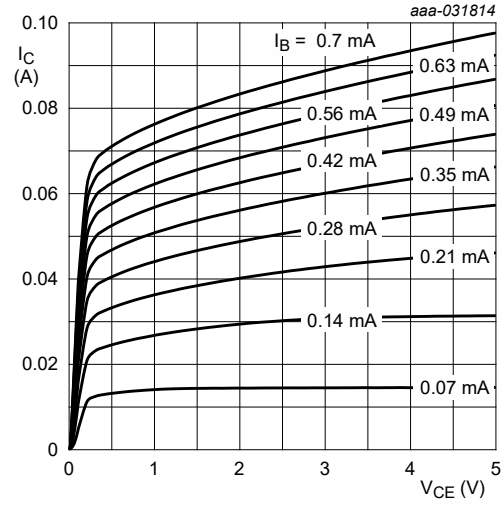
[1] See section "Test information" for resistor calculation and test conditions

[2] Characteristics of built-in transistor



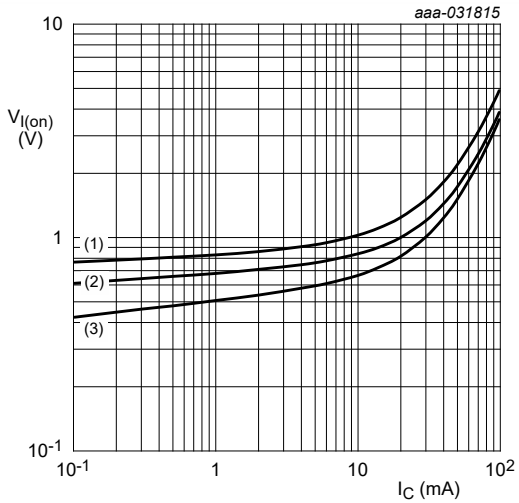
$V_{CE} = 5 \text{ V}$
 (1) $T_{amb} = 100 \text{ }^\circ\text{C}$
 (2) $T_{amb} = 25 \text{ }^\circ\text{C}$
 (3) $T_{amb} = -40 \text{ }^\circ\text{C}$

Fig. 4. NHDTC123JT-Q: DC current gain as a function of collector current; typical values



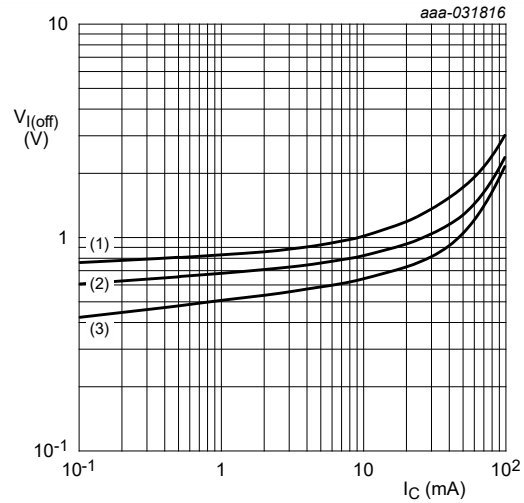
$T_{amb} = 25 \text{ }^\circ\text{C}$

Fig. 5. NHDTC123JT-Q: Collector current as a function of collector-emitter voltage; typical values



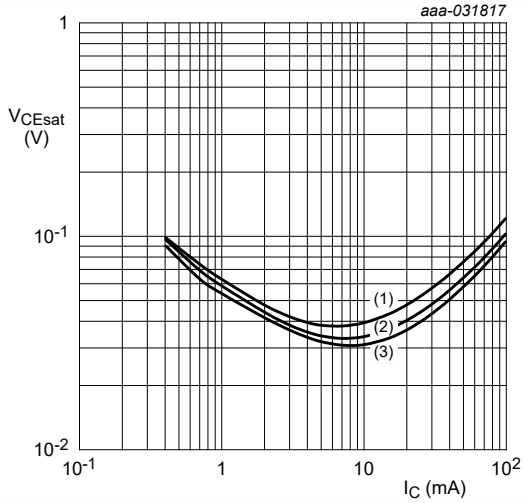
$V_{CE} = 0.3 \text{ V}$
 (1) $T_{amb} = -40 \text{ }^\circ\text{C}$
 (2) $T_{amb} = 25 \text{ }^\circ\text{C}$
 (3) $T_{amb} = 100 \text{ }^\circ\text{C}$

Fig. 6. NHDTC123JT-Q: On-state input voltage as a function of collector current; typical values



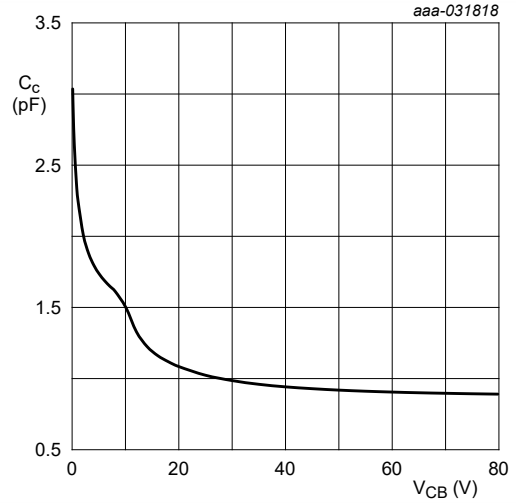
$V_{CE} = 5 \text{ V}$
 (1) $T_{amb} = -40 \text{ }^\circ\text{C}$
 (2) $T_{amb} = 25 \text{ }^\circ\text{C}$
 (3) $T_{amb} = 100 \text{ }^\circ\text{C}$

Fig. 7. NHDTC123JT-Q: Off-state input voltage as a function of collector current; typical values



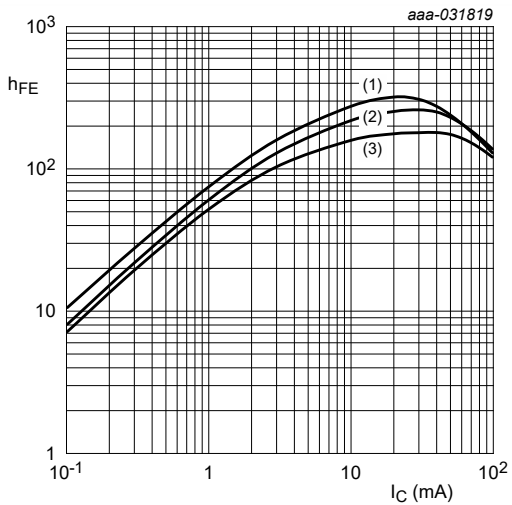
$I_C/I_B = 20$
 (1) $T_{amb} = 100\text{ °C}$
 (2) $T_{amb} = 25\text{ °C}$
 (3) $T_{amb} = -40\text{ °C}$

Fig. 8. NHDTC123JT-Q: Collector-emitter saturation voltage as a function of collector current; typical values



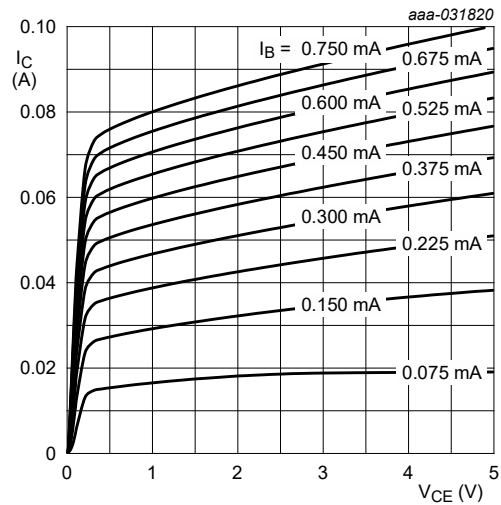
$f = 1\text{ MHz}$
 $T_{amb} = 25\text{ °C}$

Fig. 9. NHDTC123JT-Q: Collector capacitance as a function of collector-base voltage; typical values



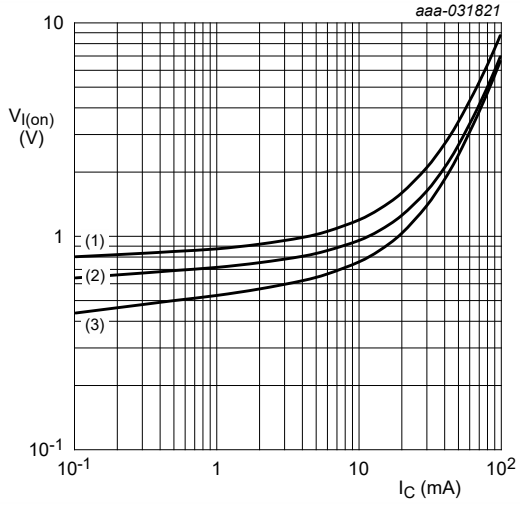
$V_{CE} = 5\text{ V}$
 (1) $T_{amb} = 100\text{ °C}$
 (2) $T_{amb} = 25\text{ °C}$
 (3) $T_{amb} = -40\text{ °C}$

Fig. 10. NHDTC143ZT-Q: DC current gain as a function of collector current; typical values



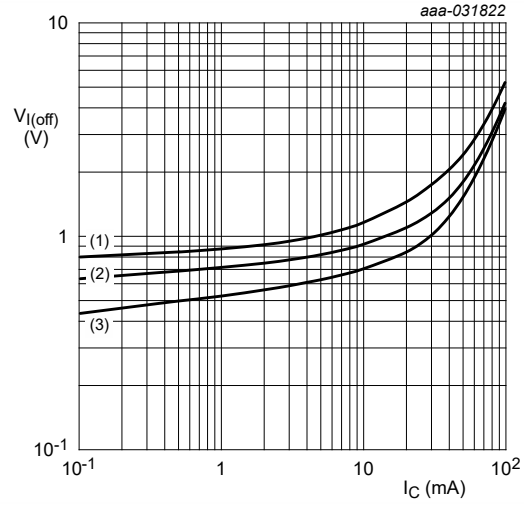
$T_{amb} = 25\text{ °C}$

Fig. 11. NHDTC143ZT-Q: Collector current as a function of collector-emitter voltage; typical values



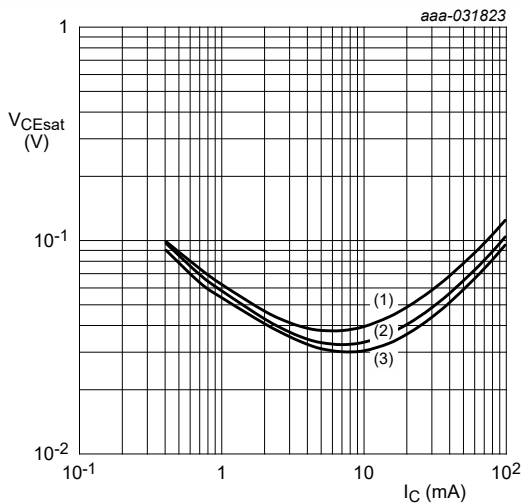
$V_{CE} = 0.3 \text{ V}$
 (1) $T_{amb} = -40 \text{ }^\circ\text{C}$
 (2) $T_{amb} = 25 \text{ }^\circ\text{C}$
 (3) $T_{amb} = 100 \text{ }^\circ\text{C}$

Fig. 12. NHDTC143ZT-Q: On-state input voltage as a function of collector current; typical values



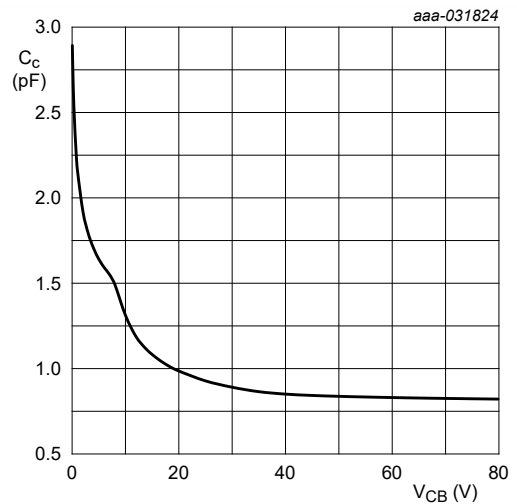
$V_{CE} = 5 \text{ V}$
 (1) $T_{amb} = -40 \text{ }^\circ\text{C}$
 (2) $T_{amb} = 25 \text{ }^\circ\text{C}$
 (3) $T_{amb} = 100 \text{ }^\circ\text{C}$

Fig. 13. NHDTC143ZT-Q: Off-state input voltage as a function of collector current; typical values



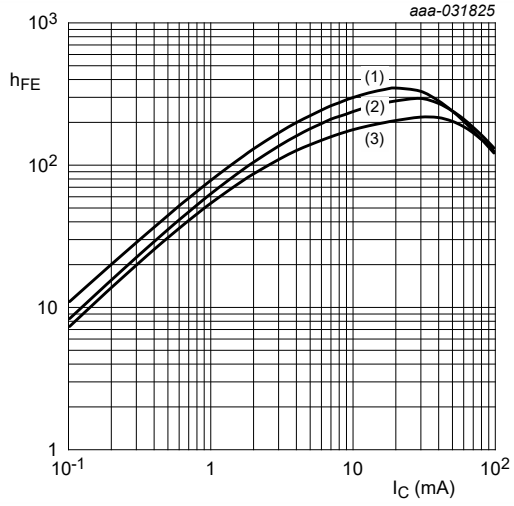
$I_C/I_B = 20$
 (1) $T_{amb} = 100 \text{ }^\circ\text{C}$
 (2) $T_{amb} = 25 \text{ }^\circ\text{C}$
 (3) $T_{amb} = -40 \text{ }^\circ\text{C}$

Fig. 14. NHDTC143ZT-Q: Collector-emitter saturation voltage as a function of collector current; typical values



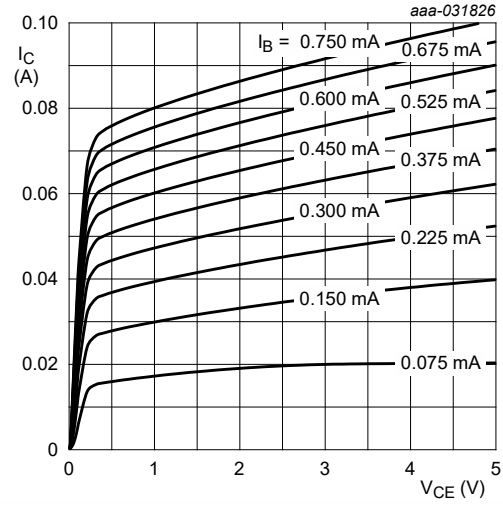
$f = 1 \text{ MHz}$
 $T_{amb} = 25 \text{ }^\circ\text{C}$

Fig. 15. NHDTC143ZT-Q: Collector capacitance as a function of collector-base voltage; typical values



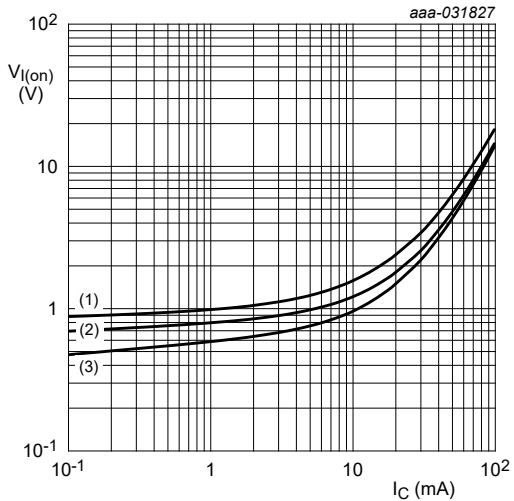
$V_{CE} = 5 \text{ V}$
 (1) $T_{amb} = 100 \text{ }^\circ\text{C}$
 (2) $T_{amb} = 25 \text{ }^\circ\text{C}$
 (3) $T_{amb} = -40 \text{ }^\circ\text{C}$

Fig. 16. NHDTC114YT-Q: DC current gain as a function of collector current; typical values



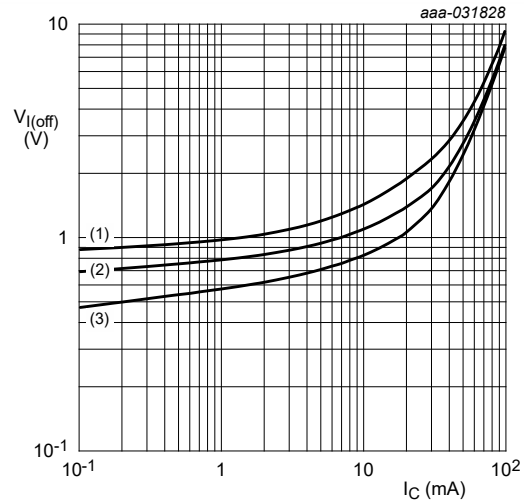
$T_{amb} = 25 \text{ }^\circ\text{C}$

Fig. 17. NHDTC114YT-Q: Collector current as a function of collector-emitter voltage; typical values



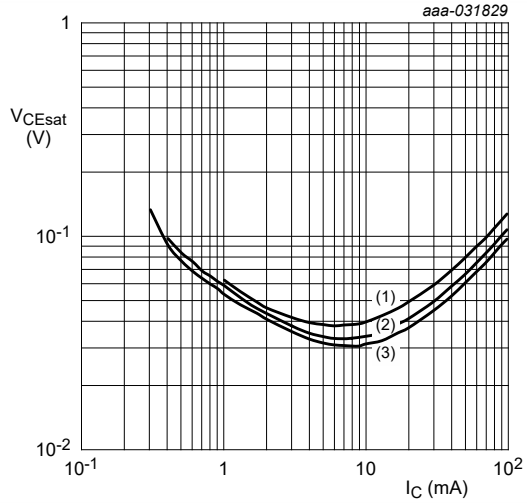
$V_{CE} = 0.3 \text{ V}$
 (1) $T_{amb} = -40 \text{ }^\circ\text{C}$
 (2) $T_{amb} = 25 \text{ }^\circ\text{C}$
 (3) $T_{amb} = 100 \text{ }^\circ\text{C}$

Fig. 18. NHDTC114YT-Q: On-state input voltage as a function of collector current; typical values



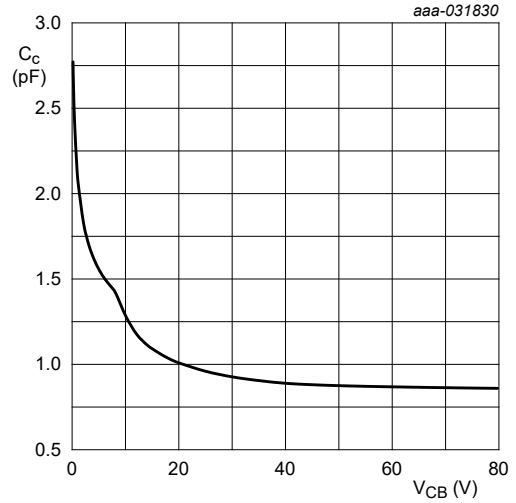
$V_{CE} = 5 \text{ V}$
 (1) $T_{amb} = -40 \text{ }^\circ\text{C}$
 (2) $T_{amb} = 25 \text{ }^\circ\text{C}$
 (3) $T_{amb} = 100 \text{ }^\circ\text{C}$

Fig. 19. NHDTC114YT-Q: Off-state input voltage as a function of collector current; typical values



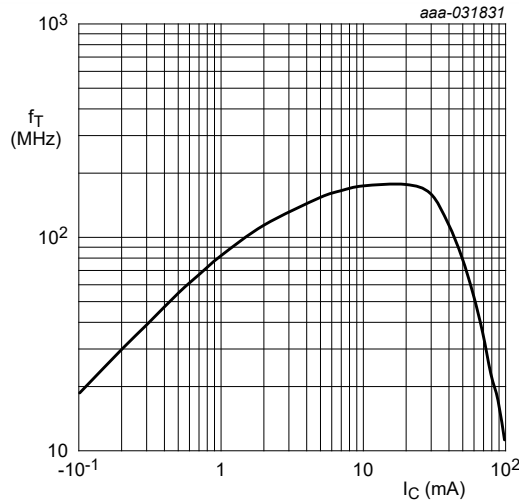
$I_C/I_B = 20$
 (1) $T_{amb} = 100\text{ °C}$
 (2) $T_{amb} = 25\text{ °C}$
 (3) $T_{amb} = -40\text{ °C}$

Fig. 20. NHDTC114YT-Q: Collector-emitter saturation voltage as a function of collector current; typical values



$f = 1\text{ MHz}$
 $T_{amb} = 25\text{ °C}$

Fig. 21. NHDTC114YT-Q: Collector capacitance as a function of collector-base voltage; typical values



$f = 100\text{ MHz}$
 $V_{CE} = 5\text{ V}$
 $T_{amb} = 25\text{ °C}$

Fig. 22. Transition frequency as a function of collector current; typical values of built-in transistor

11. Test information

Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

Resistor calculation

- Calculation of bias resistor 1 (R1)

$$R_1 = \frac{V(I_2) - V(I_1)}{I_2 - I_1}$$

- Calculation of bias resistor ratio (R2/R1)

$$\frac{R_2}{R_1} = \frac{V(I_4) - V(I_3)}{R_1 \cdot (I_4 - I_3)} - 1$$

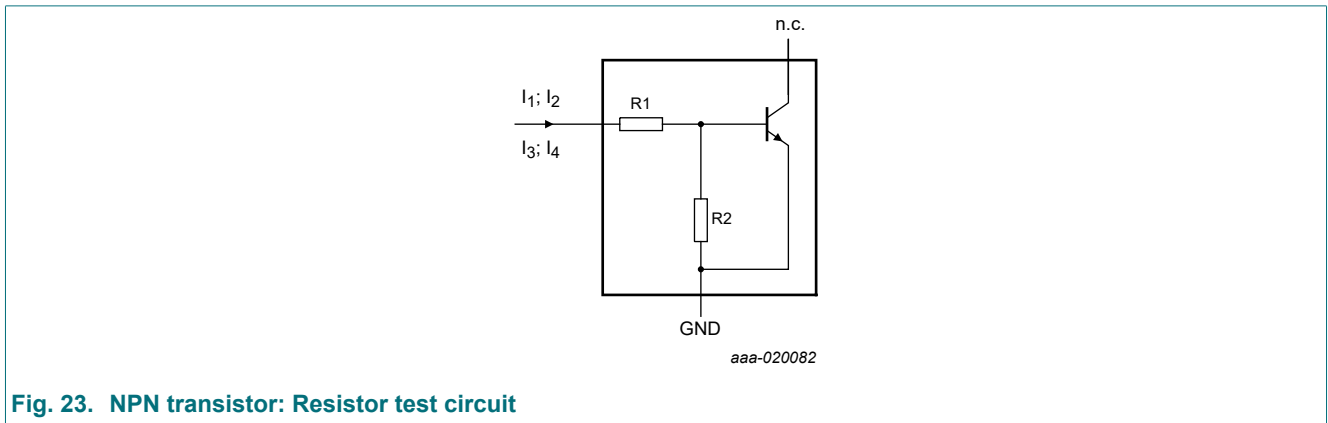


Fig. 23. NPN transistor: Resistor test circuit

Resistor test conditions

Table 9. Resistor test conditions

Type number	R1 (kΩ)	R2 (kΩ)	Test conditions			
			I ₁	I ₂	I ₃	I ₄
NHDTC123JT-Q	2.2	47	1.6 mA	2.4 mA	-55 μA	-105 μA
NHDTC143ZT-Q	4.7	47	1.2 mA	1.8 mA	-55 μA	-105 μA
NHDTC114YT-Q	10	47	800 μA	1.1 mA	-55 μA	-105 μA

12. Package outline

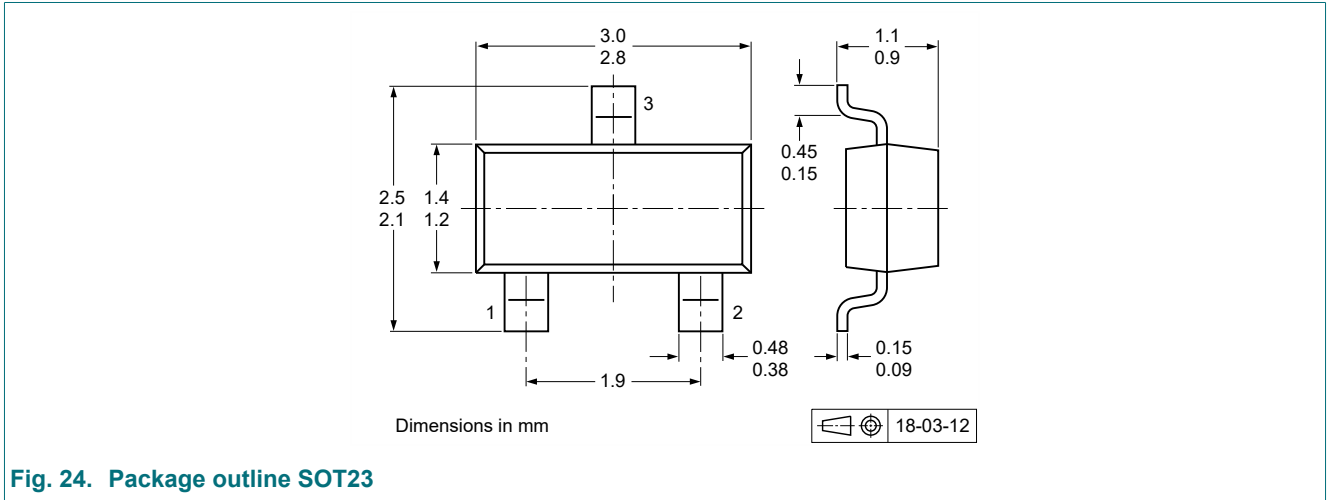


Fig. 24. Package outline SOT23

13. Soldering

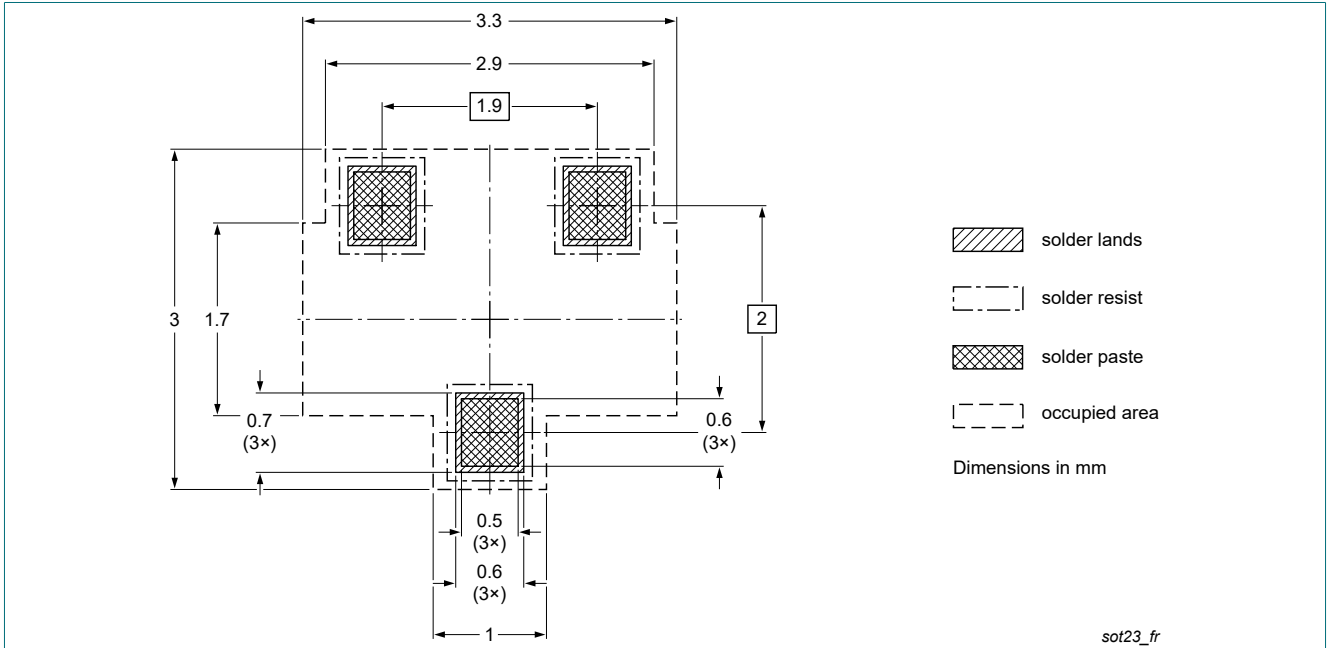


Fig. 25. Reflow soldering footprint for SOT23

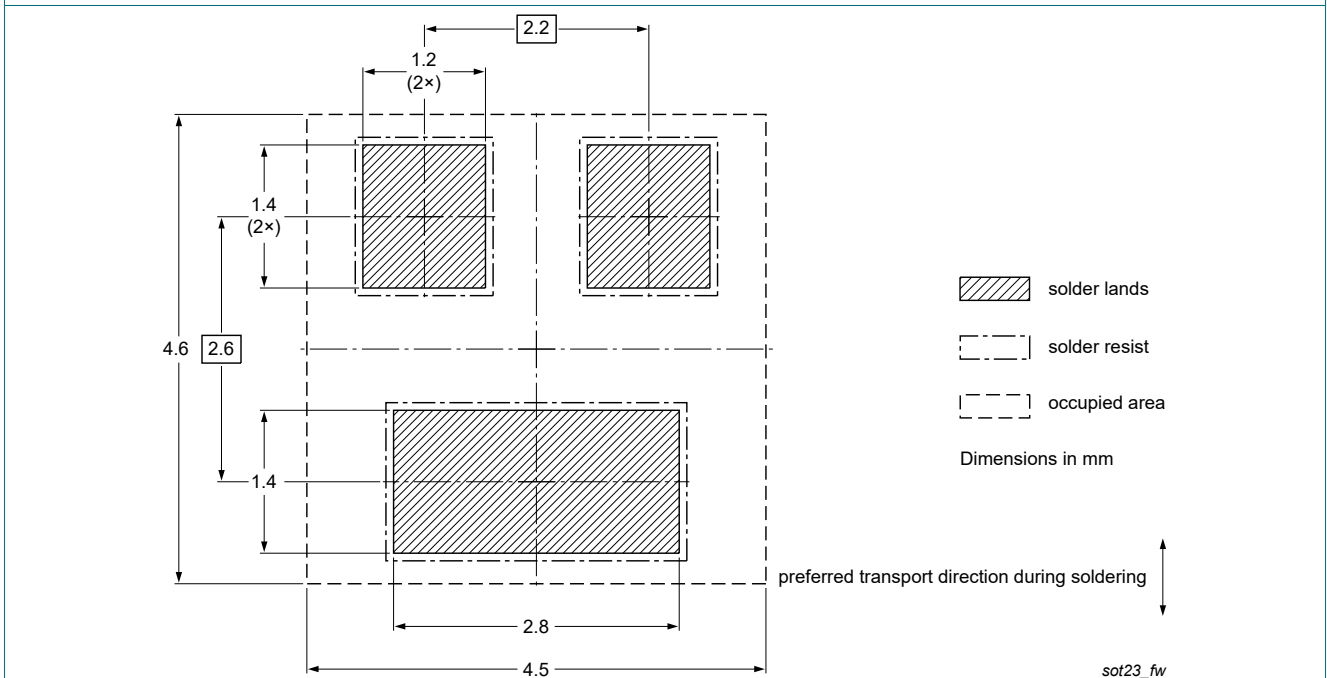


Fig. 26. Wave soldering footprint for SOT23

14. Revision history

Table 10. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
NHDTC123JT_143ZT_114YT-Q_SER v.1	20241009	Product data sheet	-	-

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <https://www.nexperia.com>.

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Date of release: 9 October 2024
